

### Trench IGBT Modules

#### SKM195GB07E3

#### **Features**

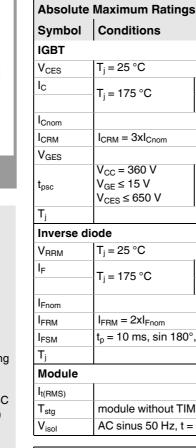
- V<sub>CE(sat)</sub> with positive temperature coefficient
- · High short circuit capability, self limiting to 6 x Icnom
- · Fast & soft inverse CAL diodes
- Insulated copper baseplate using DBC Technology (Direct Copper Bonding)
- · With integrated gate resistor

### Typical Applications\*

- · AC inverter drives
- UPS
- Electronic welders
- · Wind power
- · Public transport

### Remarks

- · Case temperature limited to  $T_c = 125$ °C max.
- Recommended T<sub>op</sub> = -40 ... +150°C
- Product reliability results valid for  $T_i = 150$ °C
- · Use of soft R<sub>G</sub> necessary



Conditions

 $T_i = 25 \, ^{\circ}C$ 

 $T_i = 175$  °C

 $I_{CRM} = 3xI_{Cnom}$ 

V<sub>CC</sub> = 360 V  $V_{GE} \le 15 \text{ V}$ 

V<sub>CES</sub> ≤ 650 V

 $T_i = 25 \,^{\circ}C$ 

 $T_i = 175 \,^{\circ}C$ 

 $I_{FRM} = 2xI_{Fnom}$ 

 $t_p = 10 \text{ ms}, \sin 180^\circ, T_i = 25 ^\circ\text{C}$ 

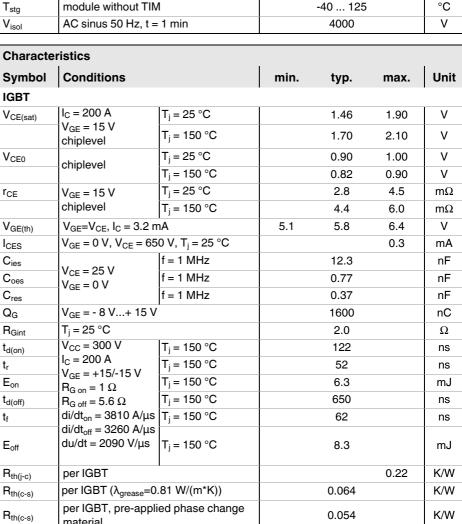
 $T_c = 25 \,^{\circ}C$ 

 $T_c = 80 \, ^{\circ}C$ 

 $T_i = 150 \, ^{\circ}C$ 

 $T_c = 25 \, ^{\circ}C$ 

 $T_c = 80 \, ^{\circ}C$ 



**Values** 

650

266

201

200

600

-20 ... 20

6

-40 ... 175

650

217

157

200

400

1470

-40 ... 175

200

Unit

٧

Α

Α

Α

Α

٧

μs

°C

V

Α

Α

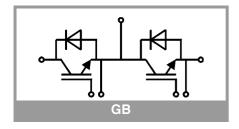
Α

Α

Α

٥С

Α



material



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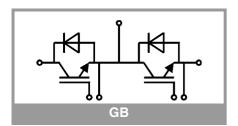
## **Typical Applications\***

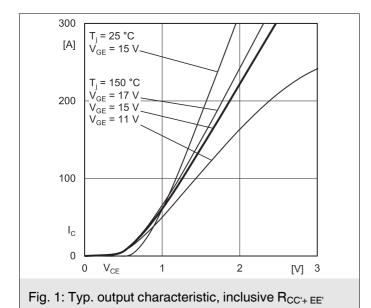
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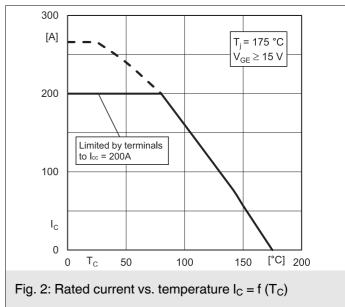
### **Remarks**

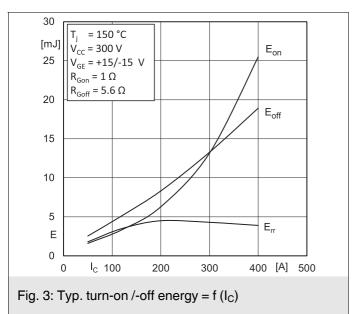
- Case temperature limited to T<sub>c</sub> = 125°C max.
- Recommended T<sub>op</sub> = -40 ... +150°C
- Product reliability results valid for  $T_j = 150^{\circ}C$
- Use of soft R<sub>G</sub> necessary

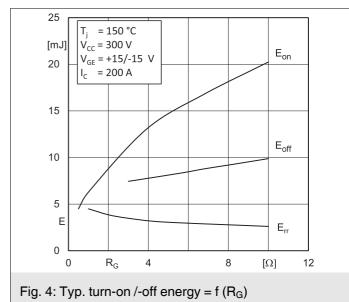
Characteristics						
Symbol	Conditions	min.	typ.	max.	Unit	
Inverse diode						
$V_F = V_{EC}$	I <sub>F</sub> = 200 A	T <sub>j</sub> = 25 °C		1.39	1.75	V
	V <sub>GE</sub> = 0 V chiplevel	T <sub>j</sub> = 150 °C		1.38	1.76	V
V <sub>F0</sub>	chiplevel	T <sub>j</sub> = 25 °C		1.04	1.24	V
		T <sub>j</sub> = 150 °C		0.85	0.99	V
r <sub>F</sub>	chiplevel	T <sub>j</sub> = 25 °C		1.76	2.6	mΩ
	·	T <sub>j</sub> = 150 °C		2.6	3.9	mΩ
I <sub>RRM</sub>	$I_F = 200 \text{ A}$ $di/dt_{off} = 3885 \text{ A/}\mu\text{s}$ $V_{GE} = \pm 15 \text{ V}$ $V_{CC} = 300 \text{ V}$	T <sub>j</sub> = 150 °C		200		Α
$Q_{rr}$		T <sub>j</sub> = 150 °C		22		μC
$E_{rr}$		T <sub>j</sub> = 150 °C		4.5		mJ
R <sub>th(j-c)</sub>	per diode				0.4	K/W
R <sub>th(c-s)</sub>	per diode (λ <sub>grease</sub> =0.81 W/(m*K))			0.069		K/W
R <sub>th(c-s)</sub>	per diode, pre-applied phase change material			0.061		K/W
Module						
L <sub>CE</sub>				30		nH
R <sub>CC'+EE'</sub>	measured per switch	T <sub>C</sub> = 25 °C		0.65		mΩ
		T <sub>C</sub> = 125 °C		1.09		mΩ
Rth <sub>(c-s)1</sub>	calculated without thermal coupling			0.017		K/W
Rth <sub>(c-s)2</sub>	including thermal coupling, Ts underneath module $(\lambda_{grease}=0.81 \text{ W/(m*K)})$			0.027		K/W
Rth <sub>(c-s)2</sub>	including thermal coupling, Ts underneath module, pre-applied phase change material			0.023		K/W
$M_s$	to heat sink M6		3		5	Nm
Mt		to terminals M5	2.5		5	Nm
						Nm
W					160	g

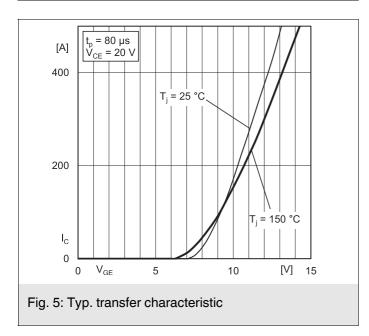


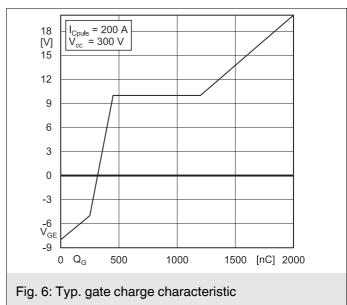


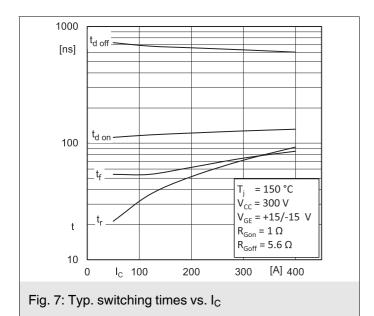


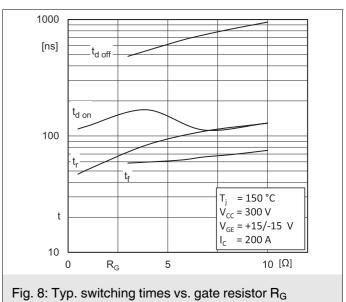


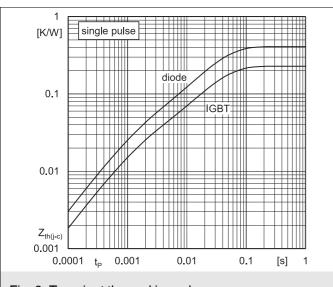














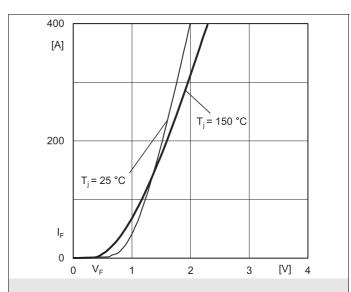


Fig. 10: Typ. CAL diode forward charact., incl.  $R_{\text{CC'+}\,\text{EE'}}$ 

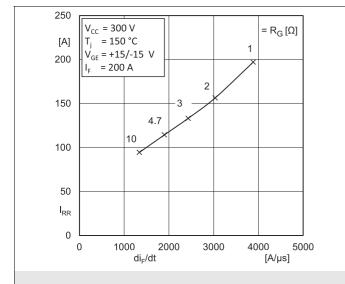


Fig. 11: CAL diode peak reverse recovery current

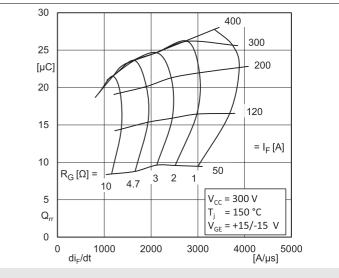
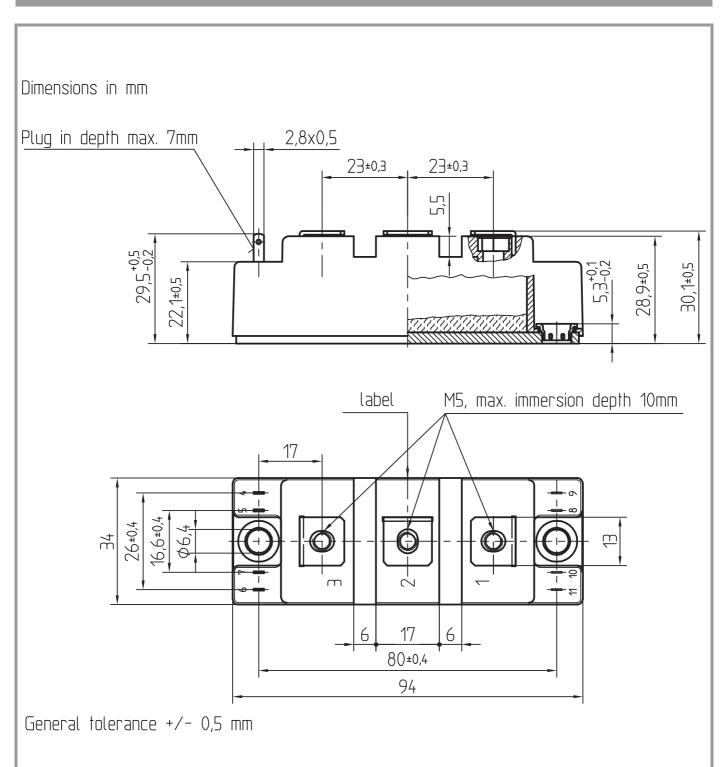
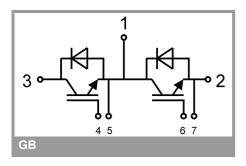


Fig. 12: Typ. CAL diode peak reverse recovery charge





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

#### \*IMPORTANT INFORMATION AND WARNINGS

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